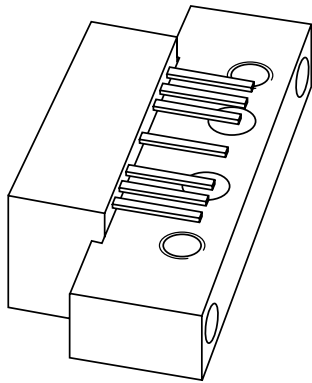


DATA SHEET



BGY885B

860 MHz, 20 dB gain push-pull
amplifier

Product specification
Supersedes data of 1997 Apr 07

2001 Nov 14

860 MHz, 20 dB gain push-pull amplifier

BGY885B

FEATURES

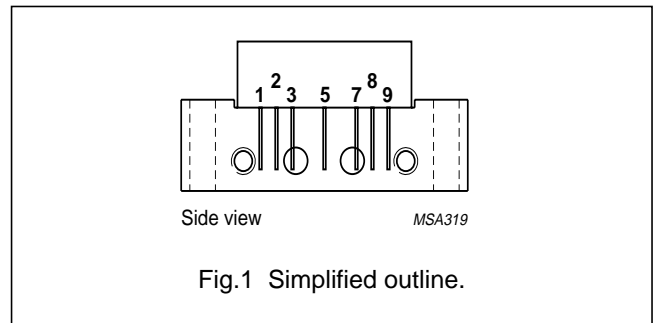
- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

The BGY885B is a hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2, 3	common
5	+V _B
7, 8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	19.5	20.5	dB
		f = 860 MHz	20	–	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	–	235	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage	–	65	dBmV
T _{stg}	storage temperature	–40	+100	°C
T _{mb}	operating mounting base temperature	–20	+100	°C

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CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G_p	power gain	f = 50 MHz	19.5	–	20.5	dB
		f = 860 MHz	20	–	–	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	–	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	–	–	±0.3	dB
S_{11}	input return losses	f = 40 to 80 MHz	20	–	–	dB
		f = 80 to 160 MHz	18.5	–	–	dB
		f = 160 to 320 MHz	17	–	–	dB
		f = 320 to 640 MHz	15.5	–	–	dB
		f = 640 to 860 MHz	14	–	–	dB
S_{22}	output return losses	f = 40 to 80 MHz	20	–	–	dB
		f = 80 to 160 MHz	18.5	–	–	dB
		f = 160 to 320 MHz	17	–	–	dB
		f = 320 to 640 MHz	15.5	–	–	dB
		f = 640 to 860 MHz	14	–	–	dB
S_{21}	phase response	f = 50 MHz	–45	–	+45	deg
CTB	composite triple beat	49 channels flat; $V_o = 44$ dBmV; measured at 859.25 MHz	–	–	–60	dB
CSO	composite second order distortion	49 channels flat; $V_o = 44$ dBmV; measured at 860.5 MHz	–	–	–60	dB
d_2	second order distortion	note 1	–	–	–68	dB
V_o	output voltage	$d_{im} = -60$ dB; note 2	57.5	59	–	dBmV
NF	noise figure	f = 50 MHz	–	–	5	dB
		f = 550 MHz	–	–	5.5	dB
		f = 650 MHz	–	–	6.5	dB
		f = 750 MHz	–	–	6.5	dB
		f = 860 MHz	–	–	7.5	dB
I_{tot}	total current consumption (DC)	note 3	–	–	235	mA

Notes

- $f_p = 55.25$ MHz; $V_p = 44$ dBmV;
 $f_q = 805.25$ MHz; $V_q = 44$ dBmV;
measured at $f_p + f_q = 860.5$ MHz.
- Measured according to DIN45004B:
 $f_p = 851.25$ MHz; $V_p = V_o$;
 $f_q = 858.25$ MHz; $V_q = V_o - 6$ dB;
 $f_r = 860.25$ MHz; $V_r = V_o - 6$ dB;
measured at $f_p + f_q - f_r = 849.25$ MHz.
- The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

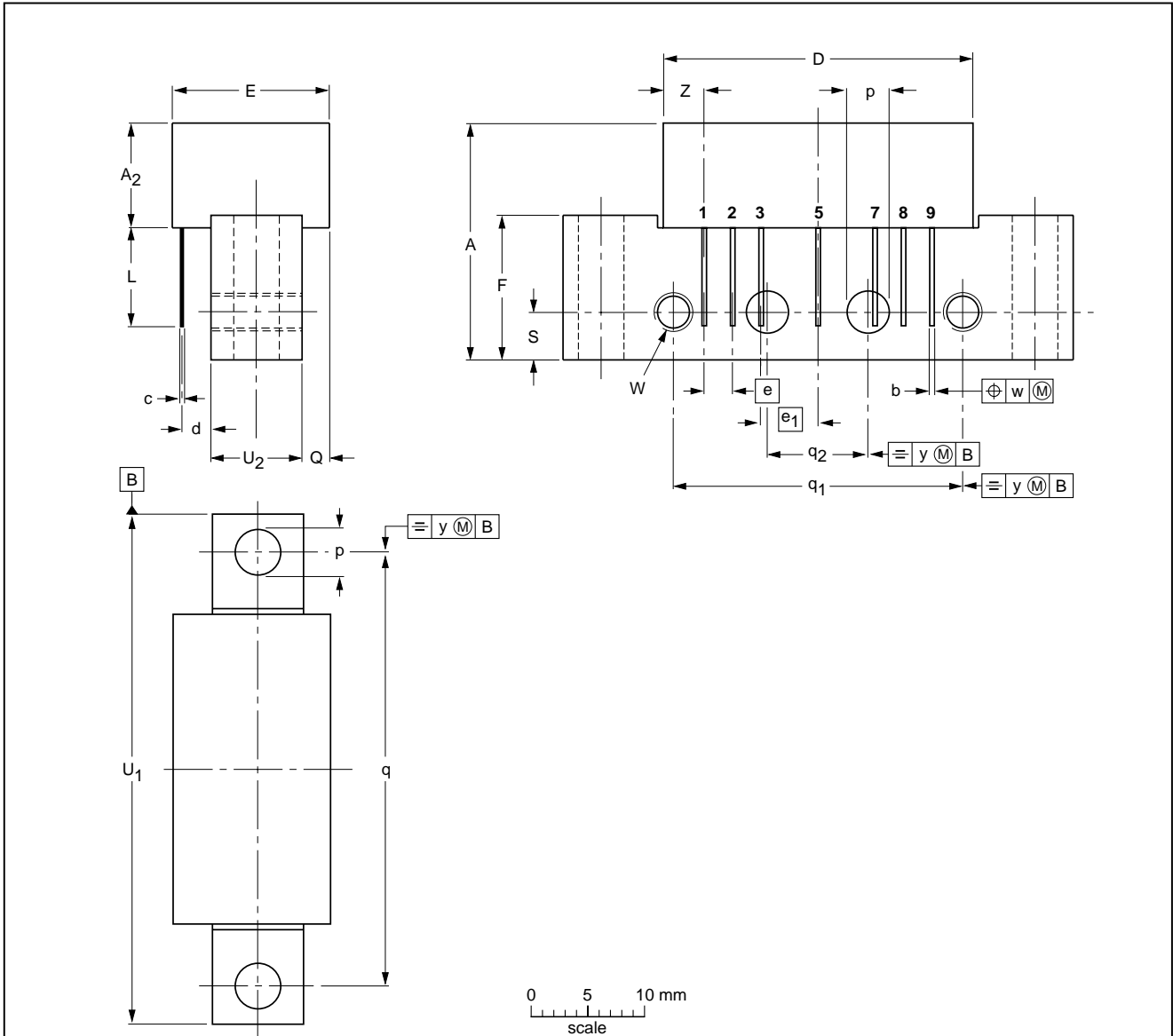
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PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₂ max.	b	c	D max.	d max.	E max.	e	e ₁	F	L min.	p	Q max.	q	q ₁	q ₂	S	U ₁ max.	U ₂	W	w	y	Z max.
mm	20.8	9.1	0.51 0.38	0.25	27.2	2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75	8	6-32 UNC	0.25	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT115J						99-02-06

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NOTES

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NOTES

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